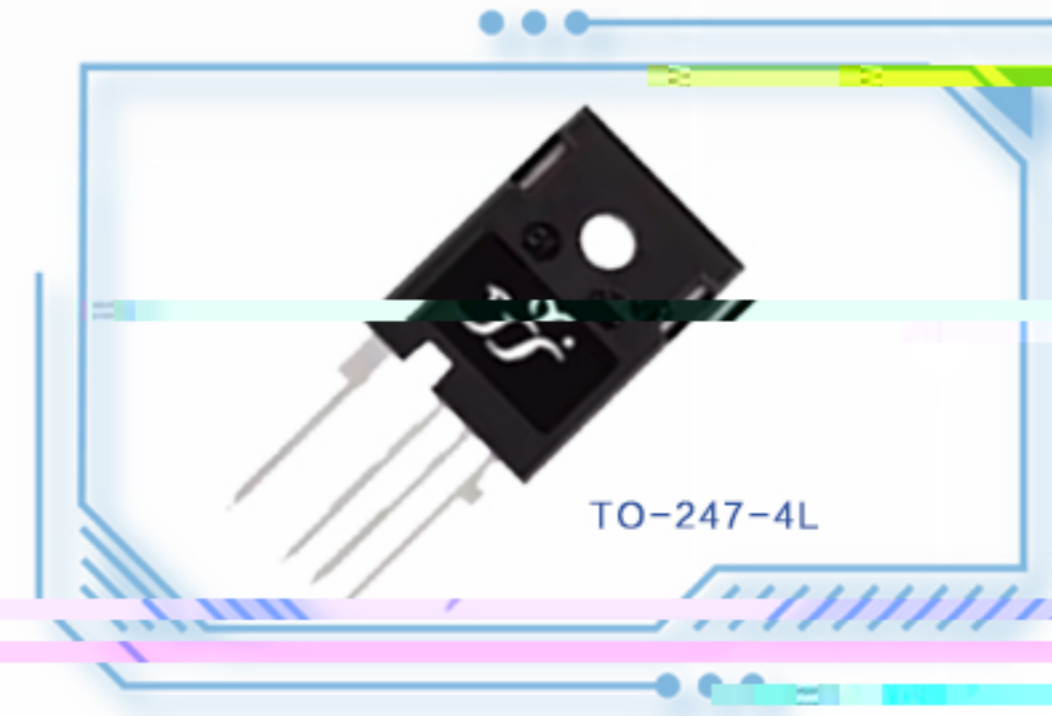
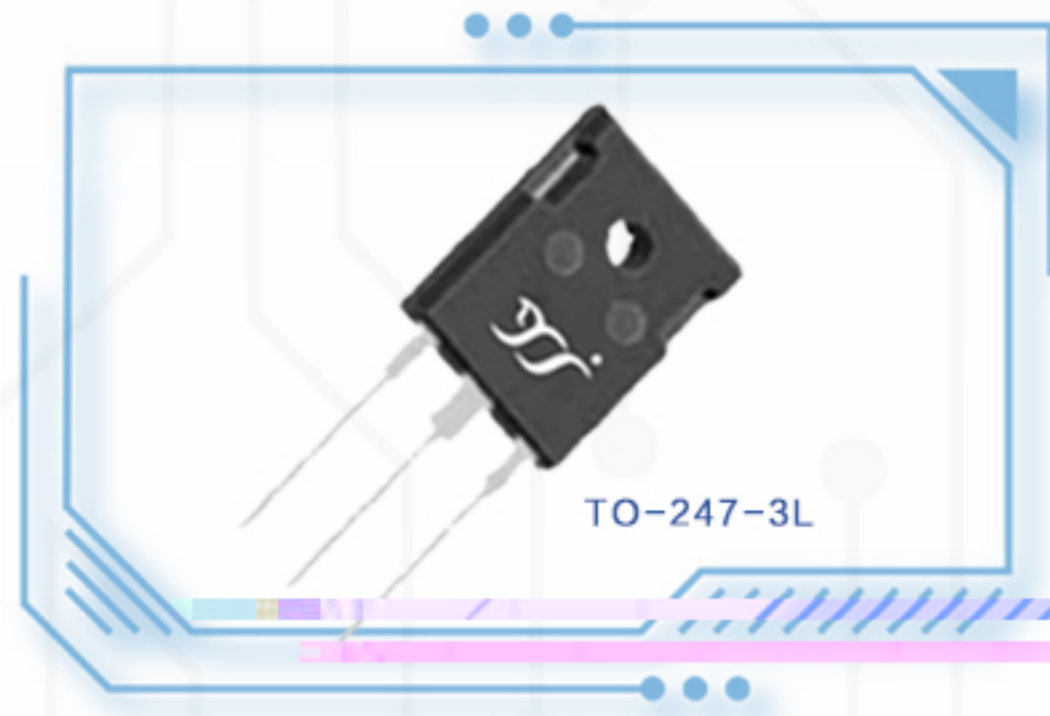


# 1200V 80mΩ SIC MOSFET

## 产品介绍

- 1. PV BOOST MOSFET
- 2. MOSFET PV
- 3. RoHS



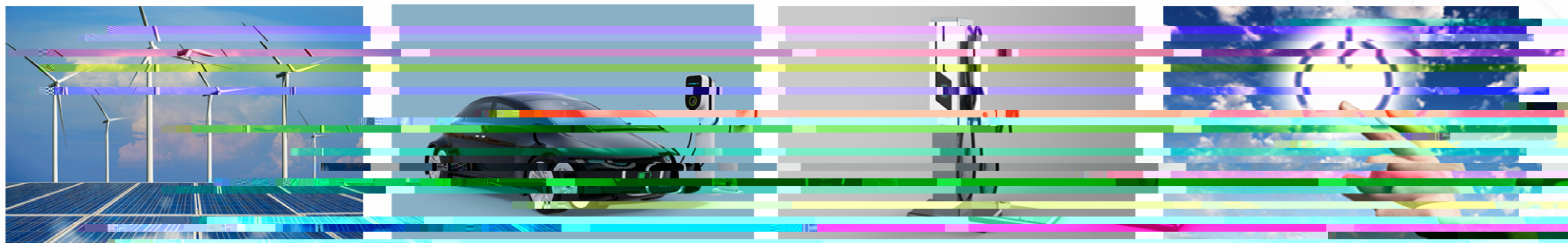
## 产品特点

- 1. 175° C)
- 2. SIC MOSFET
- 3. TO-247-3L TO-247-4L
- 4. HTRB HTGB HV-H3TRB

## 电性参数

Product	Blocking Voltage	Current Rating	Generation	Rdson(mΩ) @25°C	Gate Charge Total @25°C (nC)	Output Capacitance Coss (pF)	Power Dissipation PTOT (W)	Thermal resistance rth(j-c)	Maximum Temperature (°C)	Package
YJD212080NCTG1	1200V	38A	Gen1	77	41	58	220	0.68	175	TO247-3L
YJD212080NCFG1	1200V	39A	Gen1	77	41	58	223	0.67	175	TO247-4L

## 应用领域



EV